

Ordering number : ENA0865



SANYO Semiconductors

DATA SHEET

TN5D51 — ExPD (Excellent-Performance Power & RF Device) Separately-Excited Step-Down Switching Regulator (12V Output type)

Features

- High efficiency (ON resistance 100mΩ).
- Over current protection function (Self recovery type).
- Under voltage protection function.
- Over temperature protection function (Self recovery type).
- Soft start function (Variable subject to externally-connected capacitor).
- Stand-by mode function (Compatible with soft start terminal).

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum Input Voltage	V _{IN} max		57	V
Maximum Output Current	I _O max		5	A
SW Pin Application Reverse Voltage	V _{SW}		-1.5	V
FB Pin Maximum Input Voltage	V _{fb}		15	V
SS Pin Maximum Input Voltage	V _{SS}		7	V
Allowable Power Dissipation	P _D	T _c =25°C	2.0	W
			15	W
Operating Temperature	T _{opr}		-25 to +125	°C
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Recommend Operating Conditions

Parameter	Symbol	Conditions	Ratings	Unit
Input Voltage	V _{IN}	Ta=25°C	20 to 48	V
Output Current	I _{OUT}	Ta=25°C	0 to 5	A
Operating Temperature Range	T _{opr} rec		-10 to +85	°C

■ Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment (home appliances, AV equipment, communication device, office equipment, industrial equipment etc.). The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for applications outside the standard applications of our customer who is considering such use and/or outside the scope of our intended standard applications, please consult with us prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.

■ Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.



TN5D51

Electrical Characteristics at Ta=25°C, See Specified Test Circuit

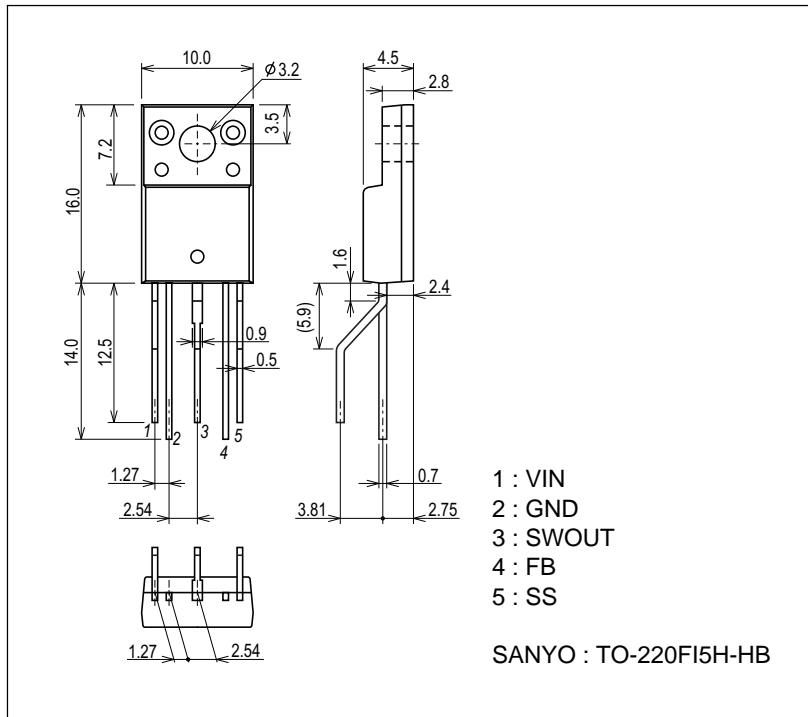
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output Voltage	V _{OUT}	V _{IN} =30V, I _{OUT} =3A	11.7	12.0	12.4	V
Efficiency	η	V _{IN} =30V, I _{OUT} =3A		92		%
Drain-to-Source On Resistance	R _{DS(on)}	I _{SW} =5A		100		mΩ
Switching Frequency	Freq	V _{IN} =30V, I _{OUT} =3A	120	150	180	kHz
Maximum Duty	Duty max	V _{IN} =30V, V _{fb} =0V	88	92	96	%
Line Regulation	ΔV_{line}	V _{IN} =20 to 40V, I _{OUT} =3A		180	360	mV
Load Regulation	ΔV_{load}	V _{IN} =30V, I _{OUT} =0.5 to 5A		100	200	mV
Output Voltage Temperature Coefficient *1	$\Delta V_O / \Delta T_a$	V _{IN} =30V, I _{OUT} =3A, T _a = -25 to +125°C		±1.2		mV / °C
Over-Current-Protection-Operation -Threshold Current	I _{ocp}	V _{IN} =30V	5.1	7.5		A
Under-Voltage-Protection-Operation -Threshold Voltage	V _{uvlo on}		7.2	8.0	8.8	V
Under-Voltage-Protection-Operation Release Voltage	V _{uvlo off}		8.1	9.0	9.9	V
Under-Voltage-Protection Hysteresis Voltage	V _{uvlo hys}			1.0		V
Over-Temperature-Protection-Operation -Threshold-Current *1	T _{tsd on}			165		°C
Over-Temperature-Protection-Operation Release Temperature *1	T _{tsd off}			140		°C
Over-Temperature-Protection Hysteresis Temperature *1	T _{tsd hys}			25		°C
SS Terminal Current	I _{SS}	V _{IN} =30V		10		μA
Standby Operating Voltage	V _{stb on}	V _{IN} =30V		0.3		V
Standby Current	I _{stb}	V _{IN} =30V, V _{SS} =0V			500	μA

Note: the values with "*"1" are our targeted values, but not guaranteed.

Package Dimensions

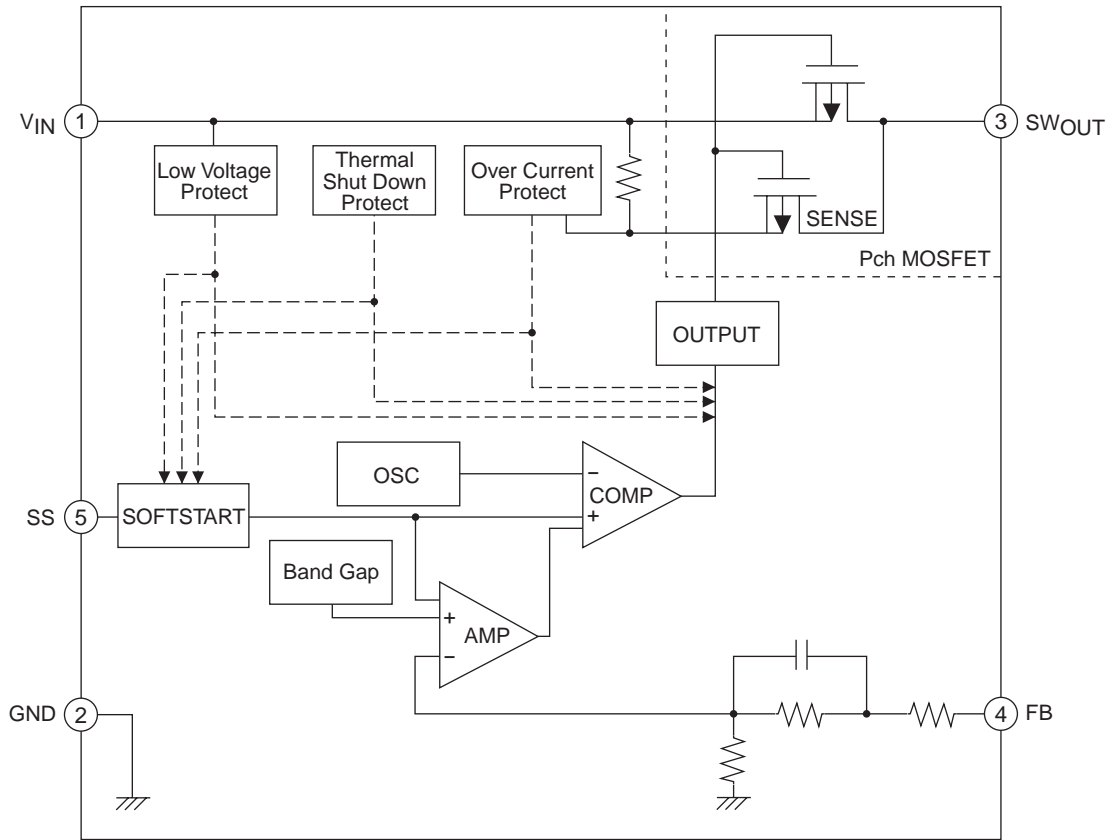
unit : mm (typ)

7527-001



TN5D51

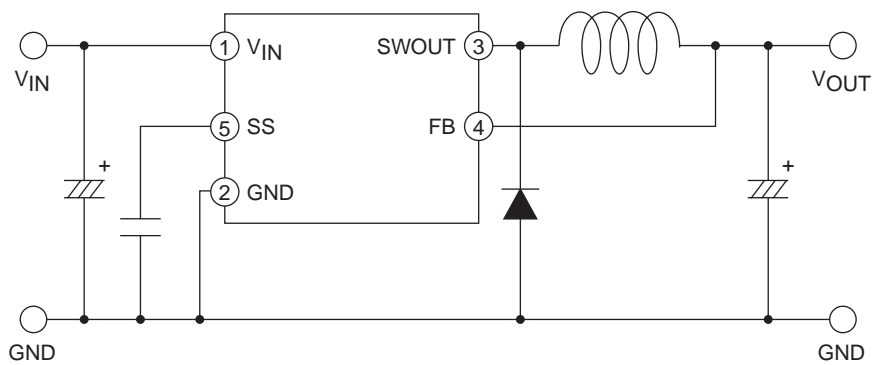
Block Diagram



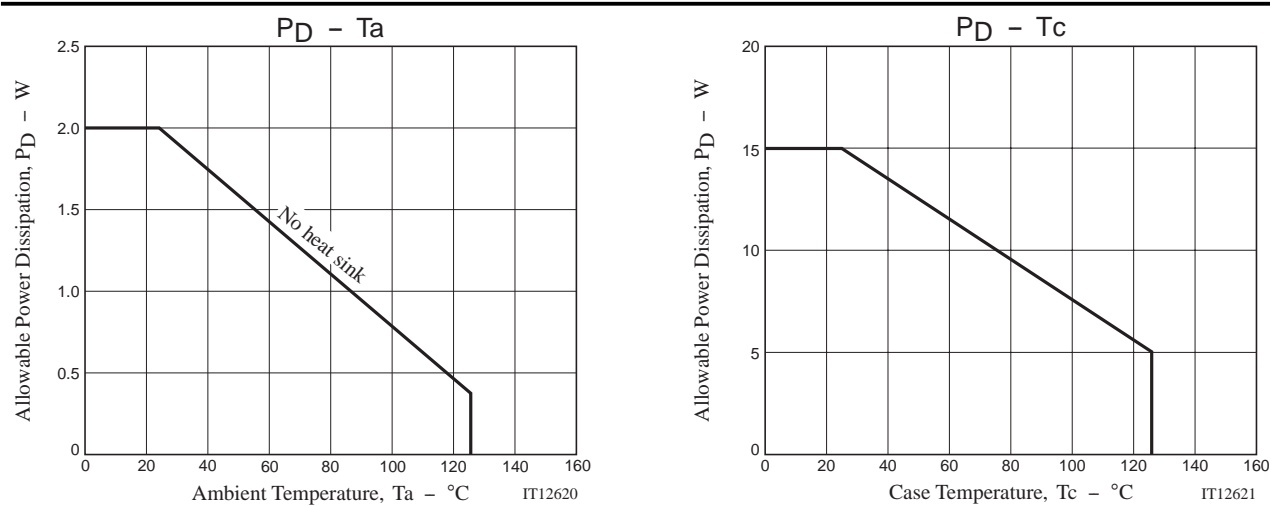
Pin Functions

Pin No.	Symbol	Function
1	V_{IN}	Power Supply Input (Maximum 57V)
2	GND	GND
3	SW _{OUT}	Pulse Voltage Output
4	FB	Feedback from Output Voltage
5	SS	For Soft Start Capacitor Connection and Standby Mode Switching

Application Circuit Example

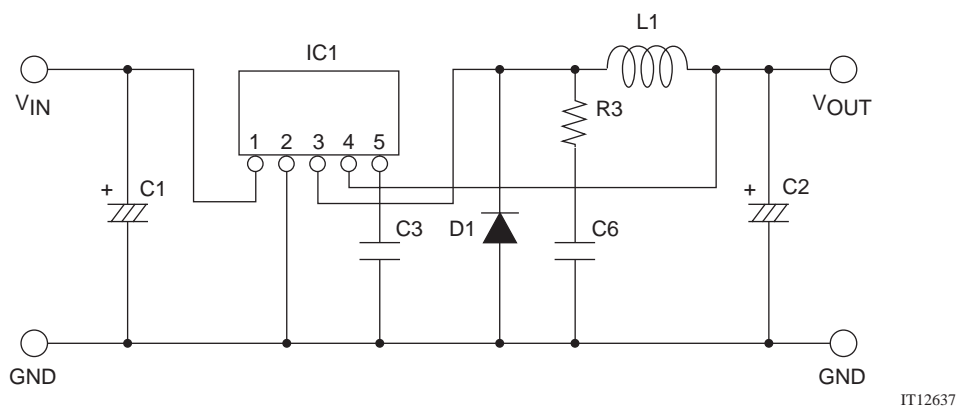


TN5D51



Specified Circuit for Electrical Characteristics

[Circuit]



[Components]

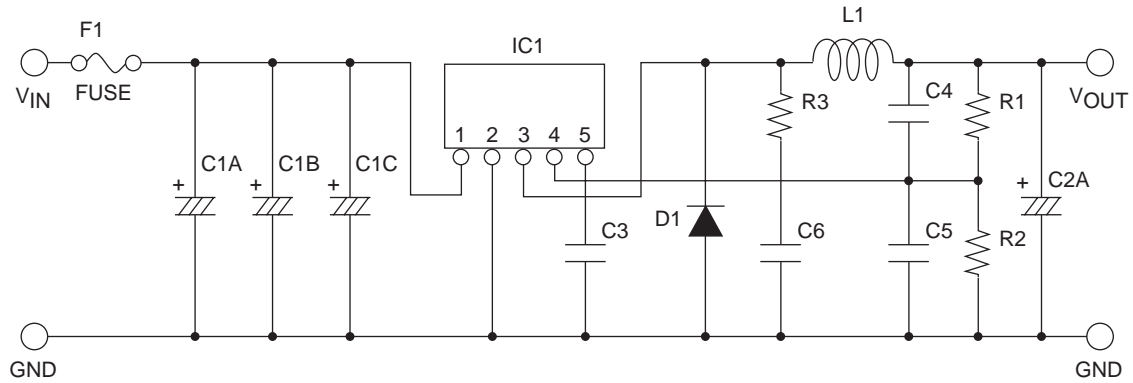
Symbol	Component	Specification
C1	Electrolytic Capacitor	3000 to 3600 μ F
C2	Electrolytic Capacitor	2000 to 2200 μ F
C3	Capacitor	0.1 μ F
C6	Ceramic Capacitor	1000pF
R3	Metal Oxide Film Resistor	47 Ω / 2W
L1	Choke Coil	100 μ H
D1	Schottky Barrier Diode	SBT250-06J

* When measuring ripple noise voltage, put 47 μ F (electrolytic capacitor) and 0.1 μ F (ceramic or film capacitor) into measuring point.

TN5D51

Evaluation Board

[Circuit]



IT12638

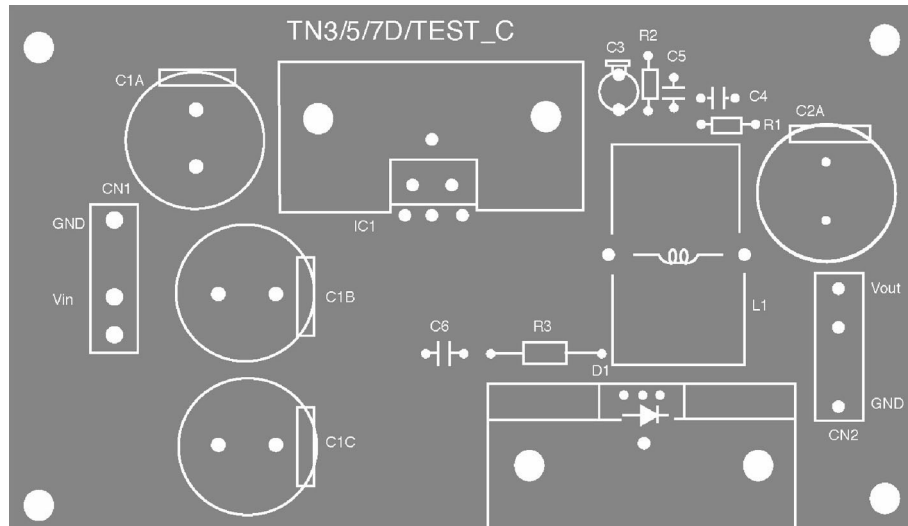
[Components]

Symbol	Component	Specification	Maker	Remark
F1	Fuse	4A	Littelfuse	452 004
C1A	Electrolytic Capacitor	1200 μ F / 80V	Nippon Chemi-Con Corp.	KZE
C1B	Electrolytic Capacitor	1200 μ F / 80V	Nippon Chemi-Con Corp.	KZE
C1C	Electrolytic Capacitor	1200 μ F / 80V	Nippon Chemi-Con Corp.	KZE
C2A	Electrolytic Capacitor	2200 μ F / 35V	Nippon Chemi-Con Corp.	KMG
C3	Film Capacitor	0.1 μ F / 100V	Matsushita Electronic Components Corp.	ECQ-B
C4	N.C.			
C5	N.C.			
C6	Ceramic Capacitor	1000pF	Murata Manufacturing Co., Ltd	
R1	Jumper Line			
R2	N.C.			
R3	Metal Oxide Film Resistor	47 Ω / 2W	Matsushita Electronic Components Corp.	
L1	Choke Coil	HK-10S100-1010	TOHO ZINC CO.,LTD	100 μ H
D1	Schottky Barrier Diode	SBT250-06J	SANYO Semiconductor Co., Ltd	

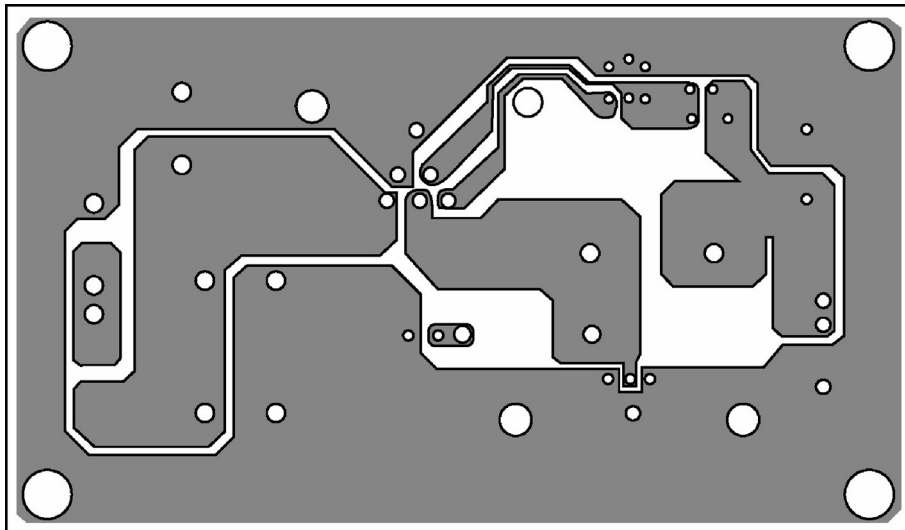
TN5D51

Recommended PWB Pattern

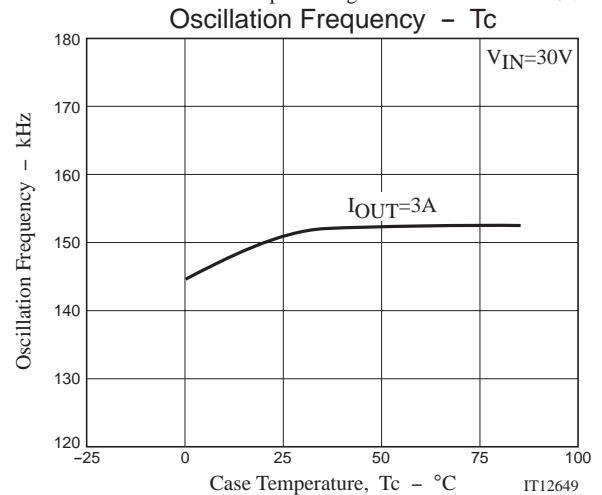
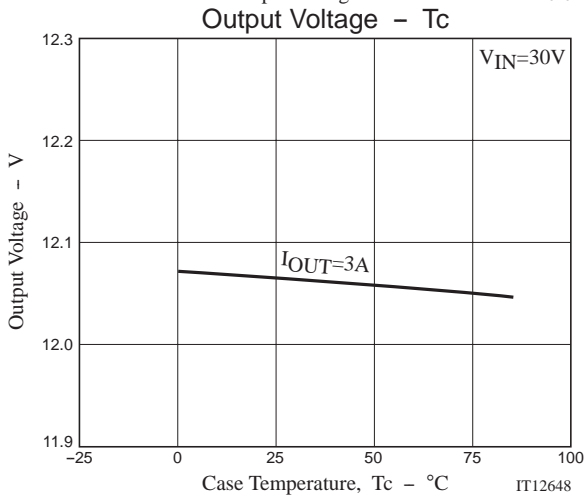
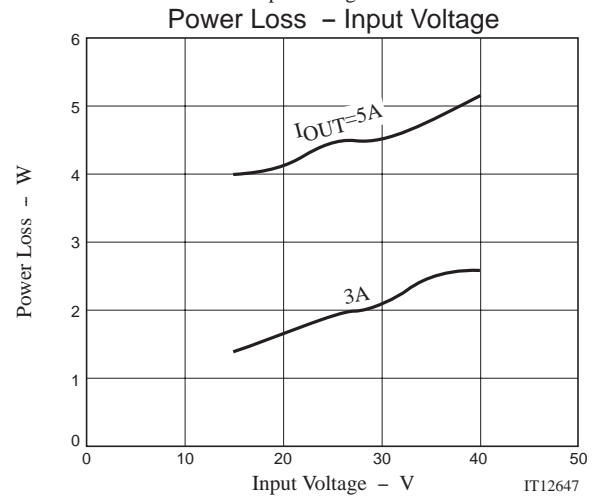
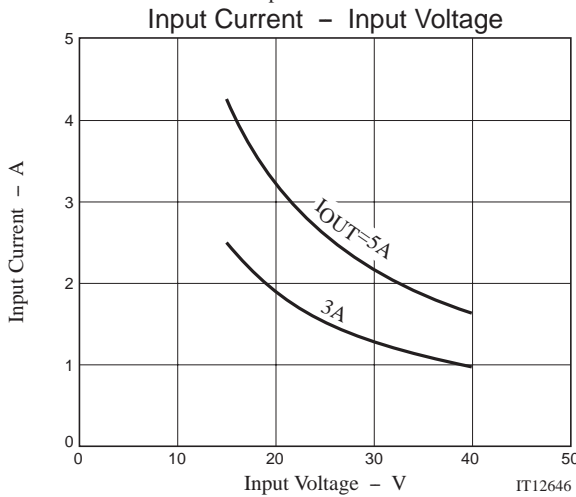
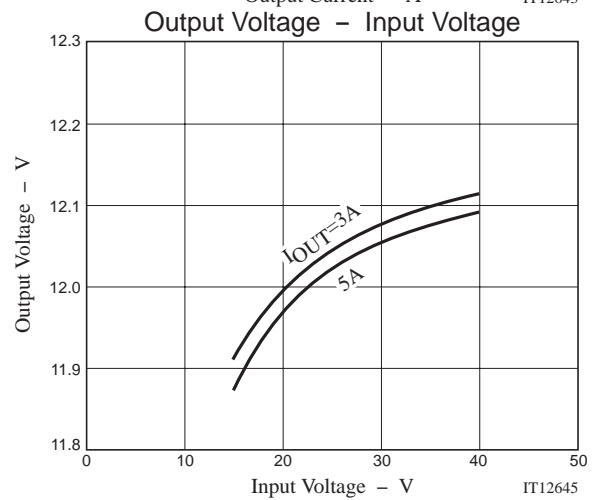
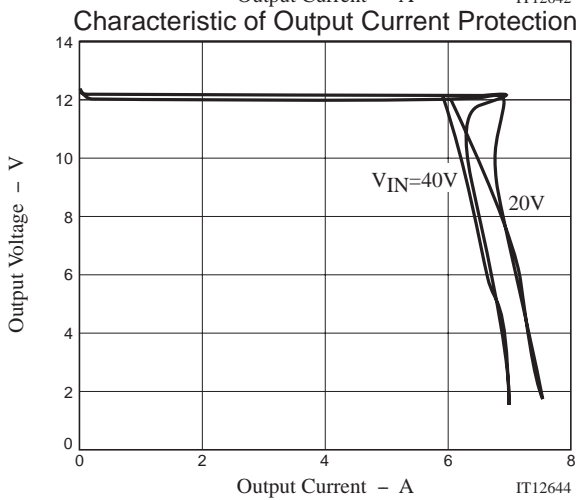
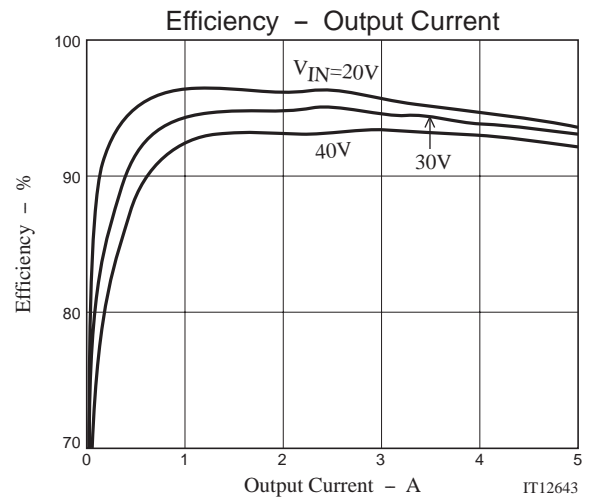
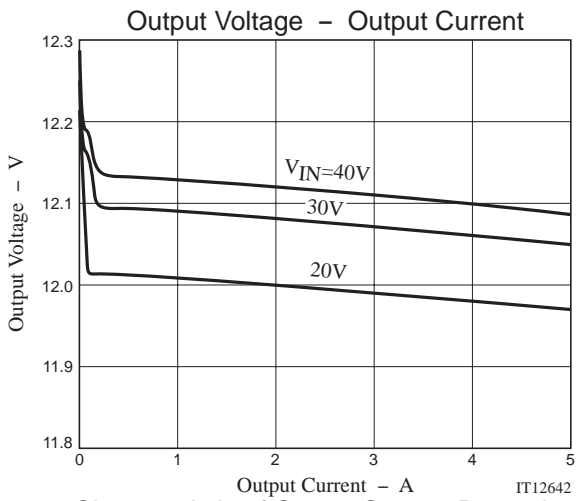
TO-220FI5H-HB Specification Silk Printing (Top View)



TO-220FI5H-HB Specification Pattern (Perspective View)

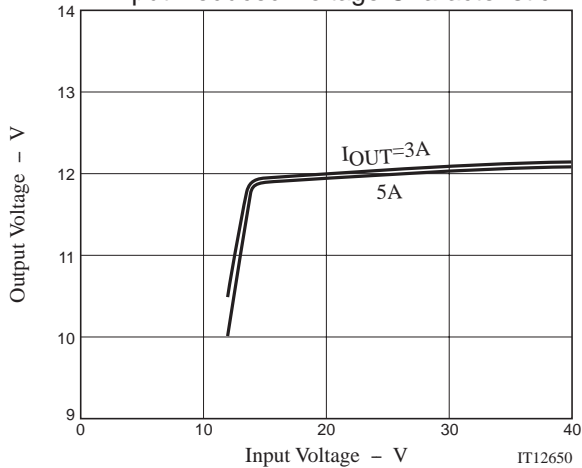


TN5D51

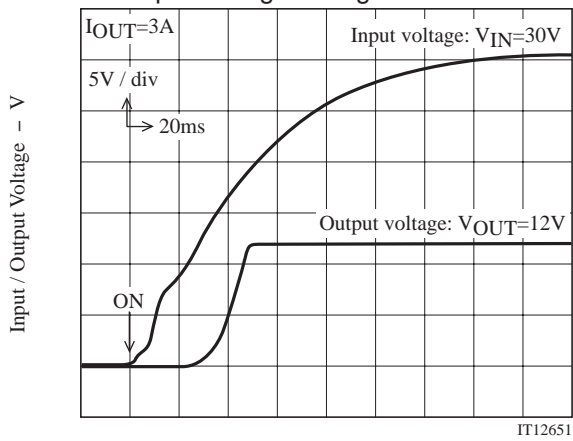


TN5D51

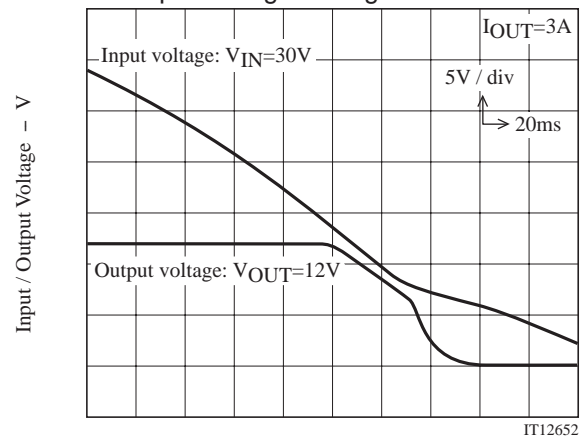
Input Reduced-Voltage Characteristic



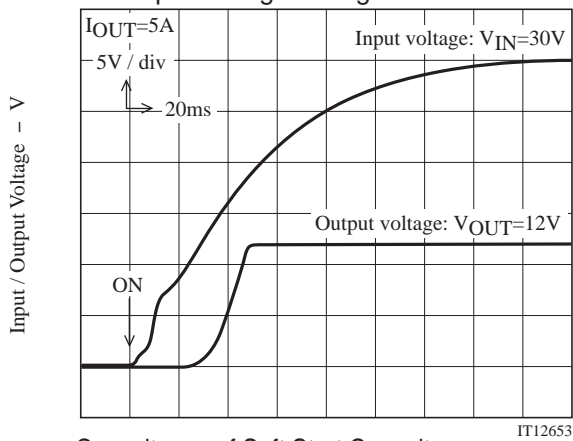
Output Voltage Rising Characteristic



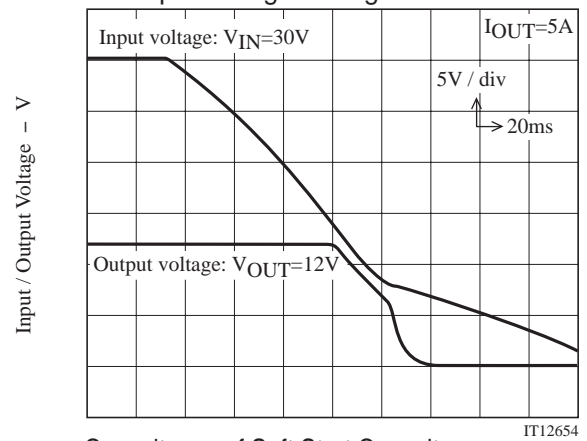
Output Voltage Falling Characteristic



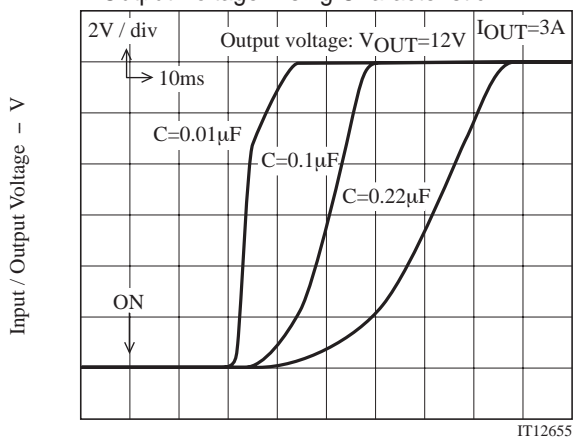
Output Voltage Rising Characteristic



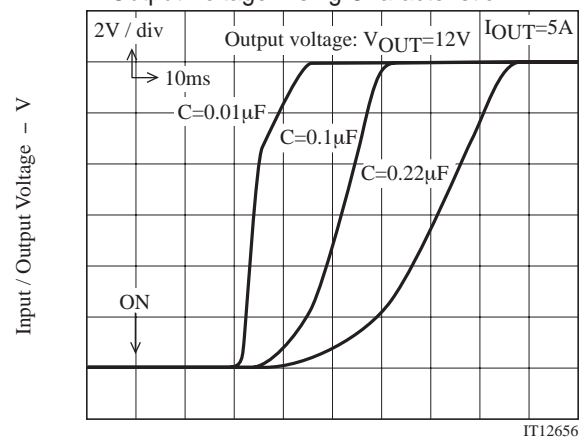
Output Voltage Falling Characteristic



Capacitance of Soft Start Capacitor – Output Voltage Rising Characteristic



Capacitance of Soft Start Capacitor – Output Voltage Rising Characteristic



TN5D51

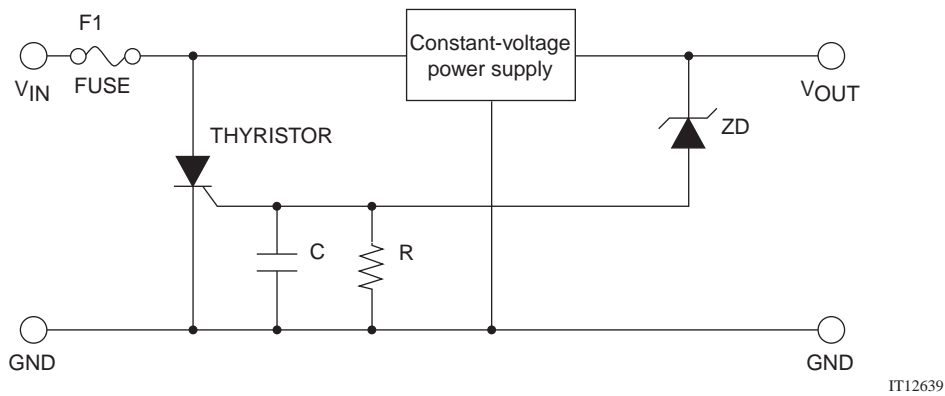
Example of Over-voltage Protection Circuit.

Generally, in constant-voltage power supply circuit, output voltage will become higher than the specified value (over-voltage state) in case of any failures or PC board solderability defects. To minimize the damage caused by this over voltage, we recommend setting an over-voltage protection circuit.

In designing, the following confirmations are necessary in actual circuit.

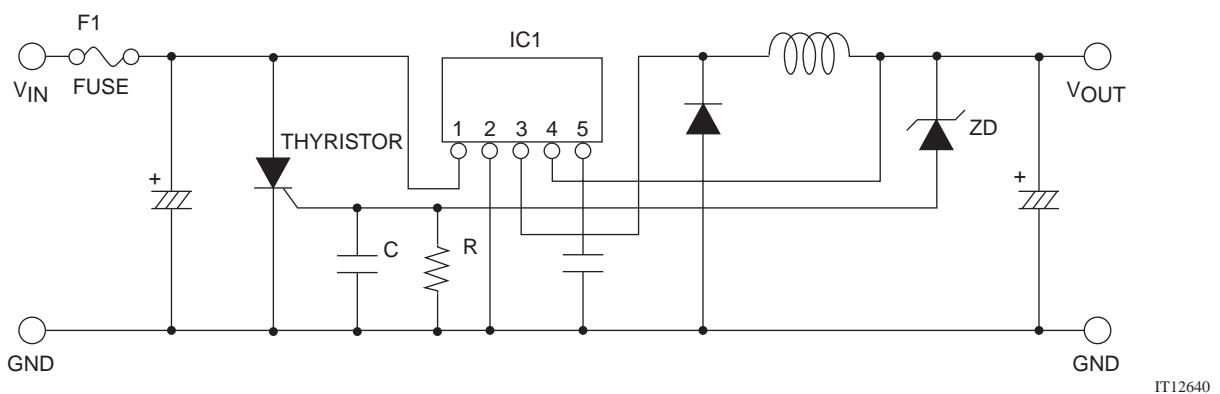
- 1) How the over-voltage protection circuit operates and its effects.
- 2) Is there any malfunction due to ambient temperature change of each device or exogenous noises?

Over-voltage Protection Circuit Example



Example of Over-voltage Protection Circuit

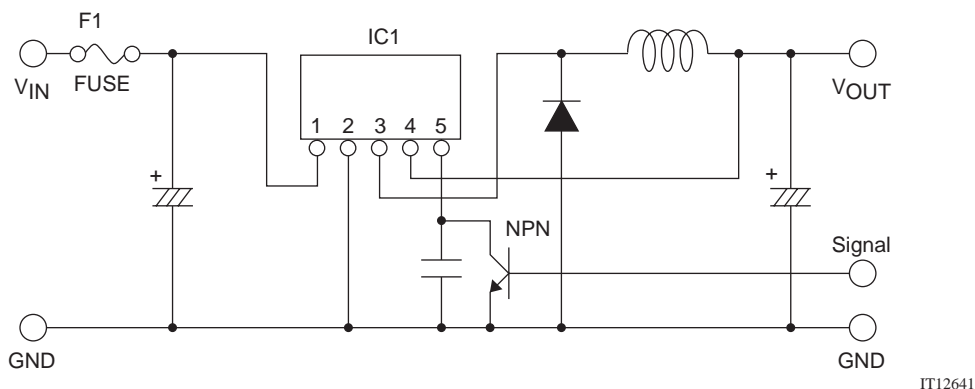
The thyristor will operate when it accept an over-voltage (V_{OUT}) signal, then the fuse is melted and the input power is cut off, then the operation of IC1 is stopped.



Continued on next page.

Continued from preceding page.

ON/OFF Control Circuit Example



- 1) How the output ON/OFF control operates and its effects.
- 2) Is there any malfunction due to the ambient temperature change of each device or exogenous noises?

- 1) Transient large current flows to VIN terminal (1 pin), so we recommend the input capacitor should be 3000μF and above. In addition, (+) (-) terminals of the input capacitor should be set near to VIN terminal (1 pin) and GND terminal (2 pin).
- 2) Large current flows to C1A to C, VIN terminal (1 pin) of IC1, SWOUT terminal (3 pin), D1, L1, and C2A. So, the wiring should be thick and short.
- 3) FB terminal (4 pin) of IC1 is the feedback terminal from output voltage. It should be near to the output capacitor C2A.

- For the purpose of ensuring the stability of oscillation, a capacitor should be inserted between SS terminal (5 pin) and GND terminal (2 pin).
- The absolute maximum rated voltage of SS terminal (5 pin) is 7V. The absolute maximum rated voltage of FB terminal (4 pin) is within the range of 5 to 30V according to the output voltage type. When a voltage equal or higher than the rated value is applied to SS terminal (5 pin) or FB terminal (4 pin) in some cases such as abnormal test, protection measures like inserting fuses should be taken.
- The built-in over-heat protection is a function to prevent the circuit from overheat state caused by transient temperature rise, but not a function to prevent from abnormal caused by a sudden heat generation. In addition, the reliability of over-heat protection function is guarantee.

- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.